PATENT COOPERATION TREATY

PCT

REC'D	1	5	NOV	2005
WIPO				PCT

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

(Chapter II of the Patent Cooperation Treaty)

(PCT Article 36 and Rule 70)

Applicant's or agent's file reference PA135296/PCT	FOR FURTHER AC	TION See Form PCT/IPEA/416					
International application No. PCT/IB2004/002404	International filing date (27.07.2004	lay/month/year) Priority date (day/month/year) 04.08.2003	ır)				
International Patent Classification (IPC	or national classification and IF						
G01N27/30, G01N27/403, G01N27/416, G01N27/48, G01N27/49							
	,						
Applicant ELEMENT SIX LIMITED et al.							
 This report is the international preliminary examination report, established by this International Preliminary Examining Authority under Article 35 and transmitted to the applicant according to Article 36. 							
2. This REPORT consists of a t	otal of 6 sheets, including th	s cover sheet.					
3. This report is also accompan	ied by ANNEXES, comprisin	j :					
a. 🛛 sent to the applicant a	and to the International Burea	u) a total of 1 sheets, as follows:					
and/or sneets cor							
☐ sheets which sup	sheets which supersede earlier sheets, but which this Authority considers contain an amendment that goes beyond the disclosure in the international application as filed, as indicated in item 4 of Box No. I and the						
		dicate type and number of electronic carrier(s)) ,					
sequence listing and/	or tables related thereto, in co	mputer readable form only, as indicated in the Su of the Administrative Instructions).	pplemental				
4. This report contains indicatio	ns relating to the following ite	ms:					
☐ Box No. I Basis of the	opinion						
☐ Box No. II Priority							
☐ Box No. III Non-establ	shment of opinion with regai	d to novelty, inventive step and industrial applicab	oility				
	ty of invention		-				
☐ Box No. V Reasoned applicability	statement under Article 35(2 ;; citations and explanations	with regard to novelty, inventive step or industria supporting such statement	1				
	cuments cited						
ŧ	ects in the international appli						
Box No. VIII Certain obs	servations on the internations	application					
Date of submission of the demand		Date of completion of this would					
outs of additional of the definant		Date of completion of this report					
01.06.2005		11.11.2005					
Name and mailing address of the interr	ational	Authorized Officer					
preliminary examining authority: European Patent Office							
D-80298 Munich	500050 annu d	Purdie, D					
Tel. +49 89 2399 - 0 Tx: Fax: +49 89 2399 - 4465	ozoooo ahuu a	Telephone No. +49 89 2399-2187	P. J. S.				

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No. PCT/IB2004/002404

_	Box No. I Basis of the repor	t				
1.	With regard to the language, the filed, unless otherwise indicated	is report is based on the international application in the language in which it was				
	This report is based on translations from the original language into the following language, which is the language of a translation furnished for the purposes of:					
	☐ international search (under Rules 12.3 and 23.1(b)) ☐ publication of the international application (under Rule 12.4) ☐ international preliminary examination (under Rules 55.2 and/or 55.3)					
2.	nave been familiaried to the rece	lith regard to the elements* of the international application, this report is based on <i>(replacement sheets which</i> ave been furnished to the receiving Office in response to an invitation under Article 14 are referred to in this aport as "originally filed" and are not annexed to this report):				
	Description, Pages					
	1-16	as originally filed				
	Claims, Numbers					
	8(part), 9-15	as originally filed				
	1-7, 8(part)	filed with telefax on 30.06.2005				
	Drawings, Sheets					
	1/2, 2/2	as originally filed				
	☐ a sequence listing and/or an	ny related table(s) - see Supplemental Box Relating to Sequence Listing				
3 .	 □ The amendments have resulted in the cancellation of: □ the description, pages □ the claims, Nos. 					
	the drawings, sheets/figs the sequence listing (spe	ecify):				
4. [}						
	the description, pages the claims, Nos.	<i>)</i> .				
	 the drawings, sheets/figs the sequence listing (spe any table(s) related to se 	ecify):				
		me or all of these sheets may be marked "superseded "				

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No. PCT/IB2004/002404

Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

1. Statement

Novelty (N) Yes: Claims 1-15

No: Claims

Inventive step (IS) Yes: Claims 1-15

No: Claims

Industrial applicability (IA) Yes: Claims 1-15

No: Claims

2. Citations and explanations (Rule 70.7):

see separate sheet

Re Item V

Reasoned statement with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

Reference is made to the following documents:

- D1: US-A-5 089 802 (YAMAZAKI SHUNPEI) 18 February 1992 (1992-02-18)
- D2: MADORE C, DURET A, HAENNI W AND PERRET A: "Detection of Trace Silver and Copper at an Array of Boron--Doped Microdisk Electrodes"
 PROCEEDINGS OF THE SYMPOSIUM ON MICROFABRICATED SYSTEMS AND MEMS, vol. 2000-19, 27 October 2000 (2000-10-27), pages 159-168, XP002306592
- D3: EP-A-1 156 136 (UNIV TOKYO) 21 November 2001 (2001-11-21)
- D4: FUJISHIMA A ET AL: "New directions in structuring and electrochemical applications of boron-doped diamond thin films" DIAMOND AND RELATED MATERIALS, ELSEVIER SCIENCE PUBLISHERS, AMSTERDAM, NL, vol. 10, no. 9-10, September 2001 (2001-09), pages 1799-1803, XP004321124 ISSN: 0925-9635
- D5: US-A-5 844 252 (SHIKATA SHIN-ICHI ET AL) 1 December 1998 (1998-12-01)
- D6: SOH K L ET AL: "CVD diamond anisotropic film as electrode for electrochemical sensing" SENSORS AND ACTUATORS B, ELSEVIER SEQUOIA S.A., LAUSANNE, CH, vol. 91, no. 1-3, 1 June 2003 (2003-06-01), pages 39-45, XP004424393 ISSN: 0925-4005

The documents regarded as being closest to the subject-matter of claim 1 is D2, which discloses a diamond based electrochemical sensing microelectrode.

The active surface of the electrode disclosed in D2 is composed of boron-doped diamond, onto which a layer of Si_3N_4 is deposited in a way to leave exposed microdisk electrodes (see Experimental section and Fig. 1).

The subject-matter of claim 1 differs from the disclosure in D2 in that the non-conducting layer is diamond, as opposed to Si_3N_4 , and that the diamond electrode surface extends at least partially through the non-conducting layer.

Other documents cited in the search report which are of particular relevance to the

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY (SEPARATE SHEET)

International application No.

PCT/IB2004/002404

application as a whole are D3, which discloses an array of diamond cylinders (Fig. 6), D4, which discloses a microstructured diamond film (see Fig. 2, for example), and D6, which discloses a CVD grown diamond tip array (Fig. 4). In each of these documents, the electrode disclosed is either intended, or is suitable, for use as an electrochemical microelectrode.

The remaining documents cited in the search report, D1 and D5, are of less relevance to the application as a whole, but are nevertheless relevant to the subject-matter of the claims.

D1 discloses a diamond thermistor, which does not fall within the scope of claim 1. However, during the manufacture of this thermistor there is an intermediate stage at which an object covered by the scope of claim 1 is arrived at (see Fig. 1B of D1). The teaching of D1 is nevertheless for the final device, and there is nothing that would suggest to the skilled man that the method of producing this final device should be interrupted. For this reason, D1 is not considered as a novelty destroying disclosure for the subject-matter of claim 1.

D5 discloses a diamond based field-emission device, in which diamond projections (122 in Fig. 2F) extend at least partially through a layer of nonconducting diamond (undoped diamond layer 13 in Fig. 2F). The projections of diamond in D5 are formed by etching layers 12 and 13, which are of doped and undoped diamond respectively (see D5, col. 7, lines 13-15). Thus the projections are not of electrically conducting diamond. The projections of the subject-matter of claim 1 are of electrically conducting diamond, and this feature differentiates claim 1 from the disclosure of D5.

The subject-matter of claim 1 is therefore new (Article 33(2) PCT).

The problem to be solved by the present invention may be regarded as how to provide an electrochemical sensing microelectrode which is alternative to that disclosed in D2.

The solution to this problem proposed in claim 1 of the present application is considered as involving an inventive step (Article 33(3) PCT), there being no suggestion in any of the other cited documents to either replace the non-conducting $\mathrm{Si_3N_4}$ layer with diamond, to

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY (SEPARATE SHEET)

International application No.

PCT/IB2004/002404

extend the diamond electrode surface at least partially through the non-conducting layer.

The novelty and inventiveness of each of claims 2-15 is ensured through the dependence on claim 1.

WO 2005/012894

PCT/IB2004/002404

-17-

CLAIMS:

- 1. An electrochemical sensing microelectrode comprising a diamond layer formed from electrically non-conducting diamond and containing one or more pins or projections of electrically conducting diamond extending at least partially through the layer of non-conducting diamond and presenting areas of electrically conducting diamond.
- A microelectrode according to claim 1, wherein the pins or projections extend to a surface of the layer of electrically nonconducting diamond presenting areas of electrically conducting diamond co-planar with that surface.
- A microelectrode according to claim 1, wherein the areas of electrically conducting material are recessed relative with a surface of the diamond layer creating a well or reservoir in that surface.
- A microelectrode according to any one of claims 1 to 3, wherein pins or projections of electrically conducting diamond present circular areas of electrically conducting diamond.
- 5. A microelectrode according to claim 3, wherein the well or reservoir contains an additive which presents a surface co-planar with the surface in which the well or reservoir is created.
- A microelectrode according to claim 5, wherein the additive modifies the sensitivity or selectivity of the electrode behaviour.
- A microelectrode according to claim 5 or claim 6, wherein the additive is an electrochemical (bio-)chemical.
- 8. A microelectrode according to claim 1, wherein the areas of electrically conducting diamond are in electrical connection with one